TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX14F,TC74LVX14FN,TC74LVX14FT

Hex Schmitt Inverter

Note: xxxFN (JEDEC SOP) is not available in Japan.

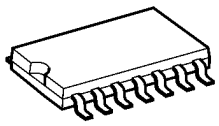
The TC74LVX14F/ FN/ FT is a high-speed CMOS HEX SCHMITT INVERTER fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

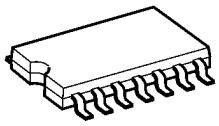
Pin configuration and function are the same as the TC74LVX04 but the inputs have hysteresis and with its schmitt trigger function, the TC74LVX14 can be used as a line receivers which will receive slow input signals.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

TC74LVX14F

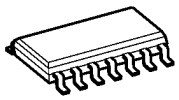


SOP14-P-300-1.27A



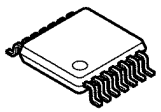
SOP14-P-300-1.27

TC74LVX14FN



SOL14-P-150-1.27

TC74LVX14FT



TSSOP14-P-0044-0.65A

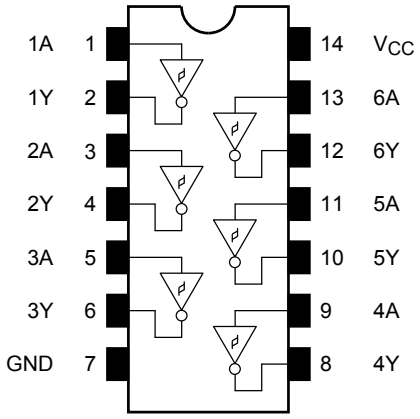
Weight

SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)

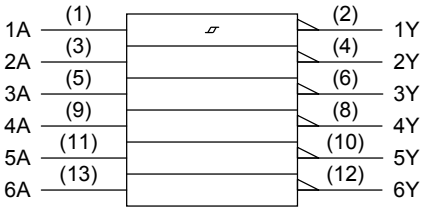
Features

- High-speed: t_{pd} = 6.8 ns (typ.) (V_{CC} = 3.3 V)
- Low power dissipation: I_{CC} = 2 μA (max) (Ta = 25°C)
- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Low niose: V_{OLP} = 0.5 V (max)
- Pin and function compatible with 74HC14

Pin Assignment (top view)



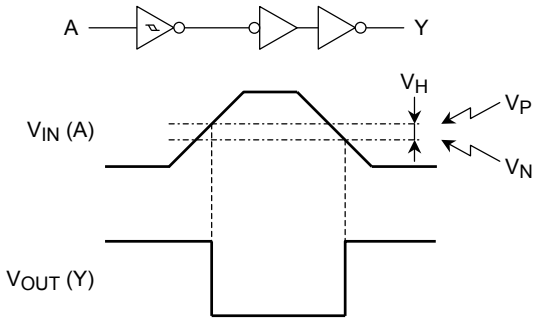
IEC Logic Symbol



Truth Table

Inputs	Outputs
A	Y
L	H
H	L

System Diagram, Waveform



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 3.6	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
					V_{CC} (V)	Min	Typ.	Max	Min	Max	
Threshold voltage	H-level	V_P	—		3.0	—	—	2.2	—	2.2	V
	L-level	V_N	—		3.0	0.9	—	—	0.9	—	
Hysteresis voltage		V_H	—		3.0	0.3	—	1.2	0.3	1.2	V
Output voltage	H-level	V_{OH}	V_{IN} = V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				I_{OH} = −50 μA	3.0	2.9	3.0	—	2.9	—	
				I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
	L-level	V_{OL}	V_{IN} = V_{IH}	I_{OL} = 50 μA	2.0	—	0	0.1	—	0.1	
				I_{OL} = 50 μA	3.0	—	0	0.1	—	0.1	
				I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
Input leakage current		I_{IN}	V_{IN} = 5.5 V or GND		3.6	—	—	±0.1	—	±1.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		3.6	—	—	2.0	—	20.0	μA

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time	t_{pLH}	—	2.7	15	—	8.7	16.3	1.0	19.5	ns
				50	—	11.2	19.8	1.0	23.0	
	t_{pHL}		3.3 ± 0.3	15	—	6.8	10.6	1.0	12.5	
				50	—	9.3	14.1	1.0	16.0	
Output to output skew	t_{osLH}	(Note 1)	2.7	50	—	—	1.5	—	1.5	ns
	t_{osHL}		3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input capacitance	C_{IN}	(Note 2)			—	4	10	—	10	pF
Power dissipation capacitance	C_{PD}	(Note 3)			—	21	—	—	—	pF

Note 1: Parameter guaranteed by design.
($t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$)

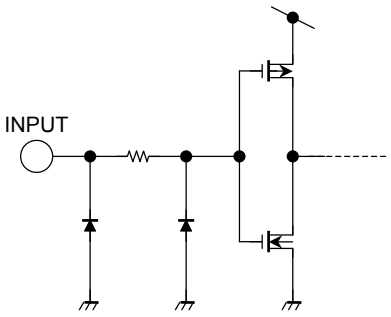
Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.
Average operating current can be obtained by the equation:
$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per gate)

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3$ ns, $C_L = 50$ pF)

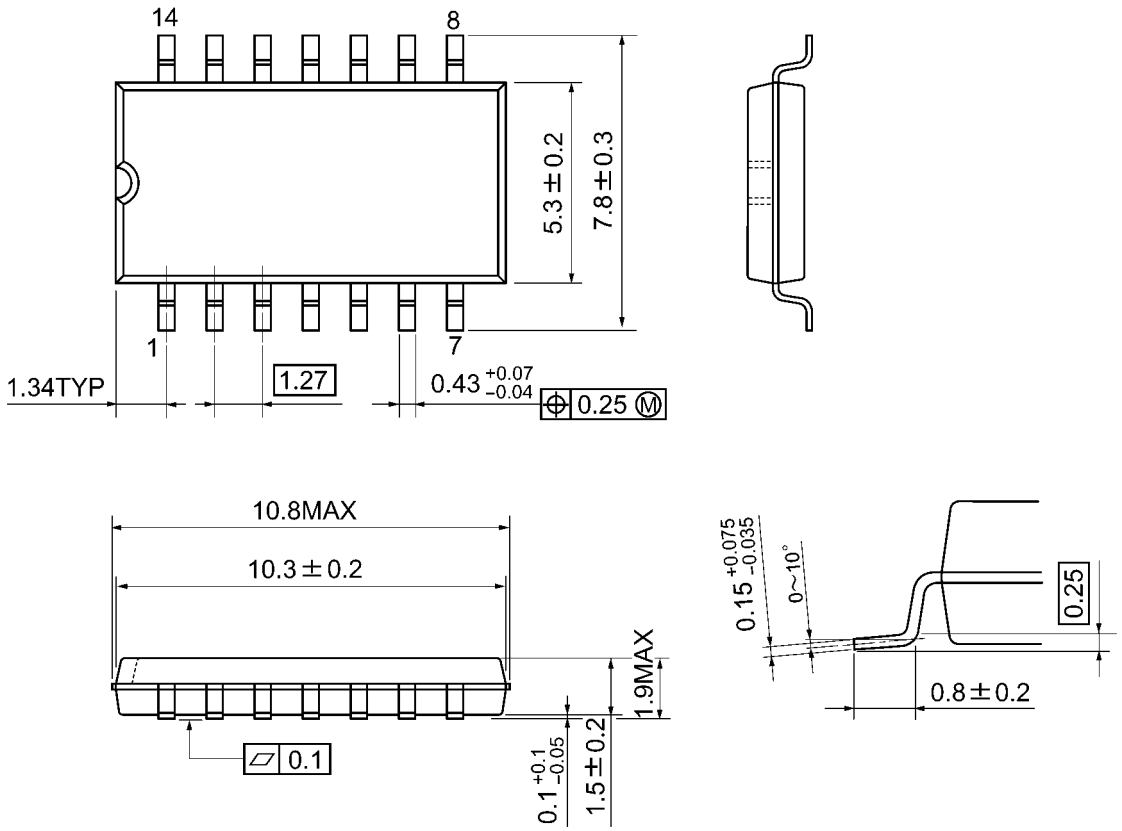
Characteristics	Symbol	Test Condition	Typ.	Limit	Unit
		V_{CC} (V)			
Quiet output maximum dynamic V_{OL}	V_{OLP}	—	3.3	0.3	0.5	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	—	3.3	−0.3	−0.5	V
Minimum high level dynamic input voltage V_{IH}	V_{IHD}	—	3.3	—	2.2	V
Maximum low level dynamic input voltage V_{IL}	V_{ILD}	—	3.3	—	0.9	V

Input Equivalent Circuit



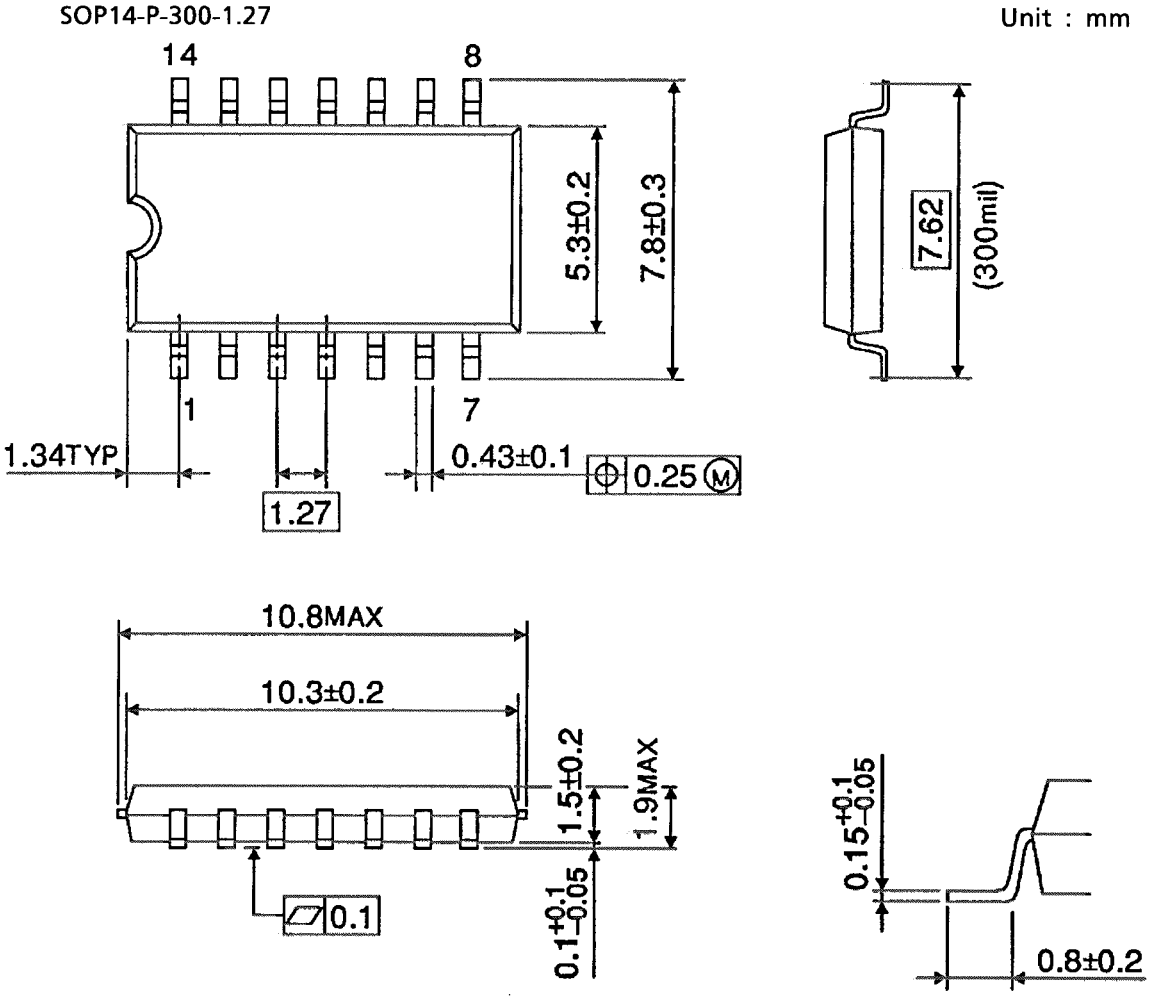
Package Dimensions

SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

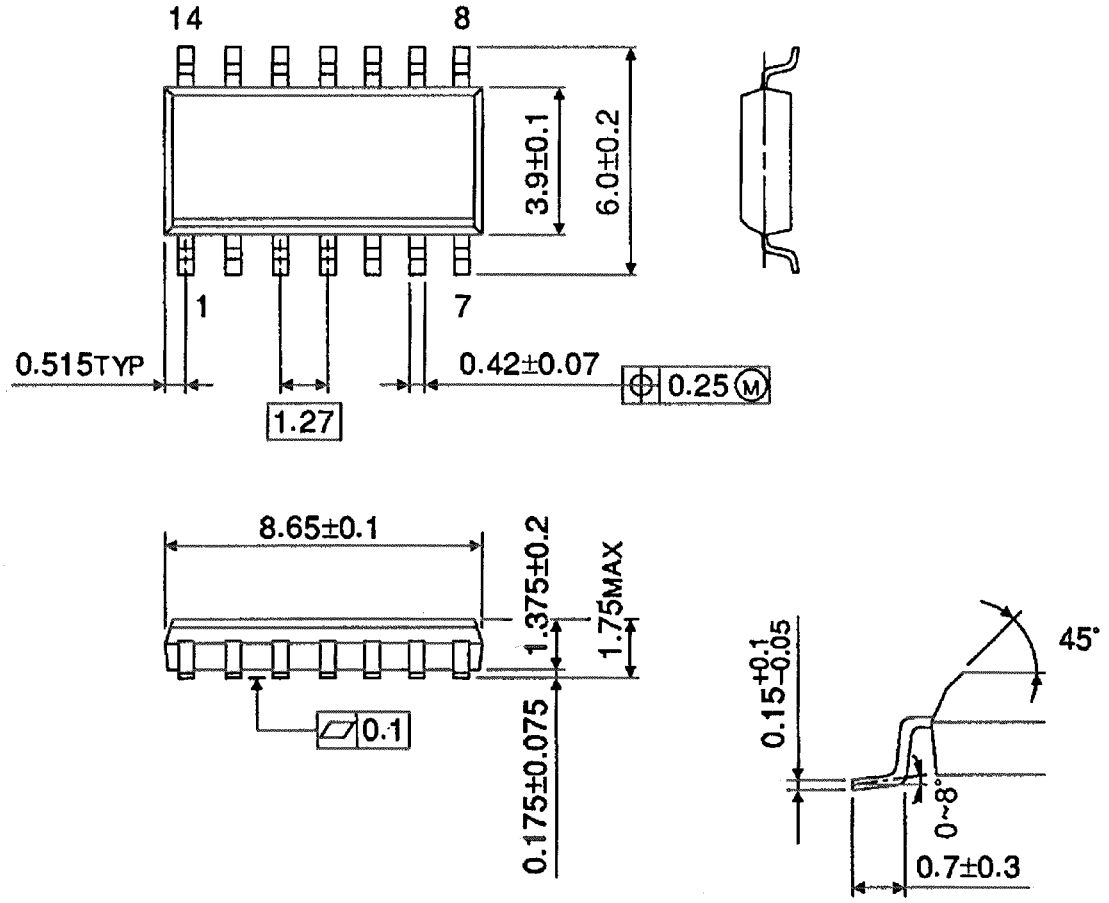
Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27 Unit : mm

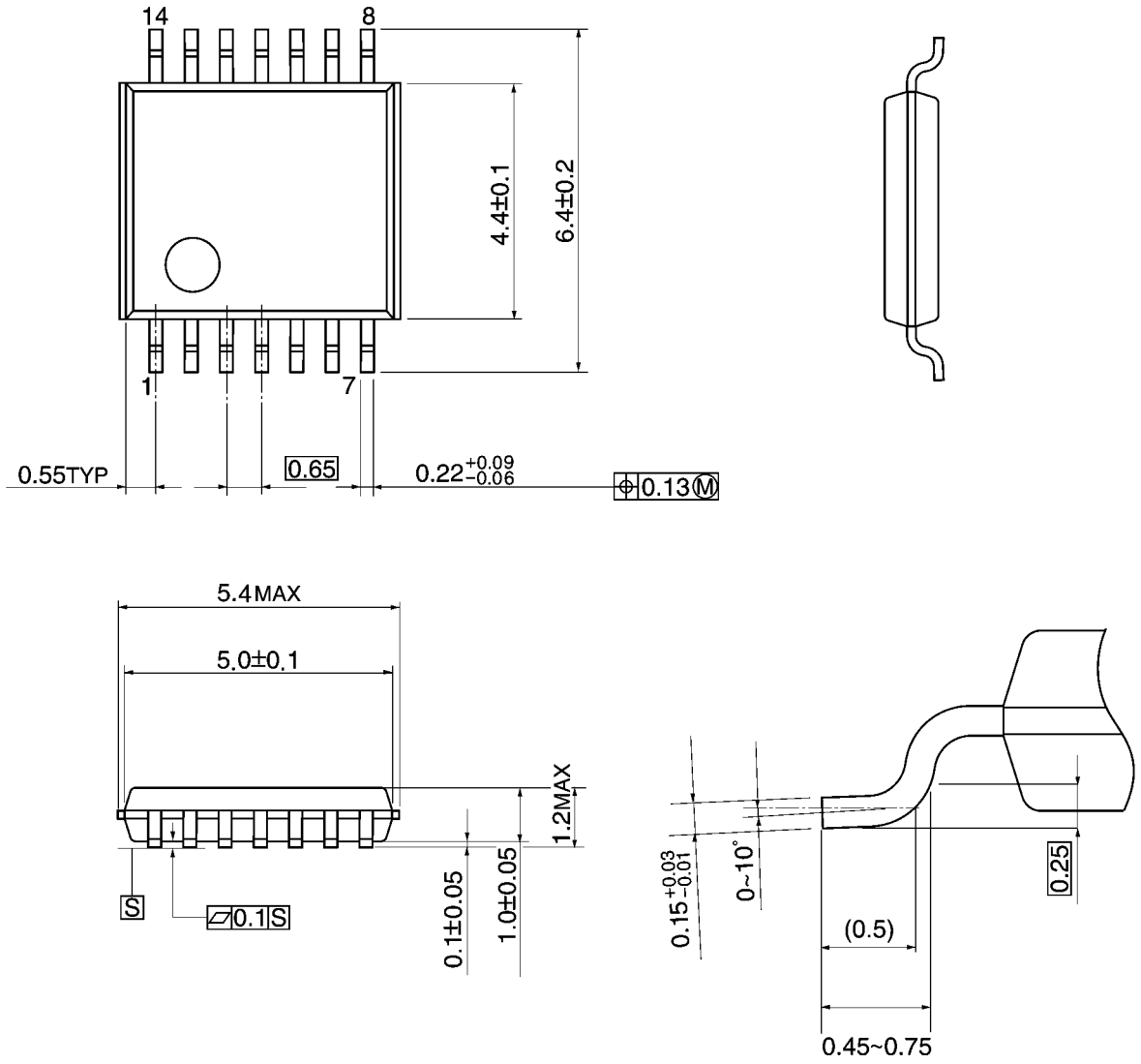


Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A Unit: mm



Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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